



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

October 28, 2024

IGI Report Number

Description

Shape and Cutting Style

Measurements

LG660444552

LABORATORY GROWN DIAMOND

EMERALD CUT

11.84 X 7.97 X 5.22 MM

GRADING RESULTS

Carat Weight

Color Grade

Clarity Grade

5.02 CARATS

E

VVS 2

ADDITIONAL GRADING INFORMATION

Polish

Symmetry

Fluorescence

EXCELLENT

EXCELLENT

NONE

Inscription(s)

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
Type II

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PROPORTIONS

Slightly Thick

15.5%

63%

46%

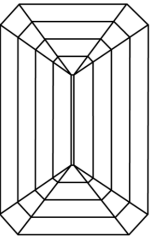
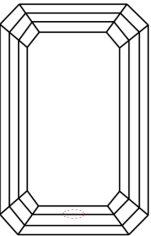
Long

65.5%



Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D

E

F

G

H

I

J

Faint

Very Light

Light

CLARITY

IF

VS¹⁻²

VS¹⁻²

SI¹⁻²

I¹⁻³

Internally Flawless

Very Very Slightly Included

Very Slightly Included

Slightly Included

Included

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